16-Channel µModule PMBus Power System Manager

FEATURES

- **Sequence, Trim, Margin and Supervise 16 Power Supplies**
- **Manage Faults, Monitor Telemetry and Create Fault Logs**
- **PMBus™ Compliant Command Set**
- **Supported by LTpowerPlay® GUI**
- **Margin or Trim Supplies to Within 0.25% of Target**
- **Fast OV/UV Supervisors Per Channel**
- **Coordinate Sequencing and Fault Management Across Multiple LTC PSM Devices**
- **Automatic Fault Logging to Internal EEPROM**
- **Operate Autonomously without Additional Software**
- Internal Temperature and Input Voltage Supervisors
- Accurate Monitoring of 16 Output Voltages, Two Input Voltages and Internal Die Temperature
- I^2C/SMBus Serial Interface
- Can Be Powered from 3.3V, or 4.5V to 15V
- Programmable Watchdog Timer
- Available in 144-Pin 15mm × 15mm BGA Package

APPLICATIONS

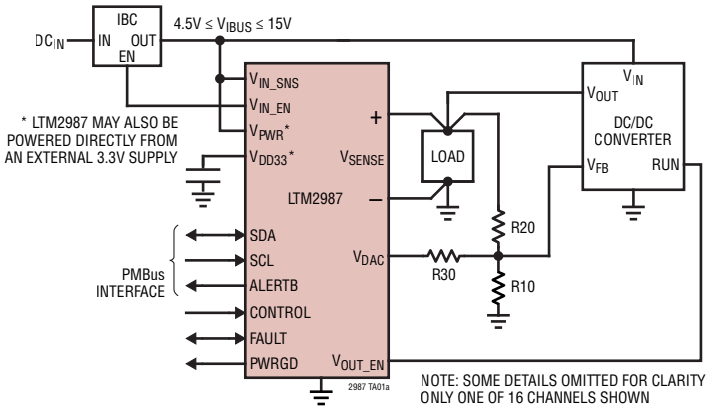
- Computers and Network Servers
- Industrial Test and Measurement
- High Reliability Systems
- Medical Imaging
- Video

DESCRIPTION

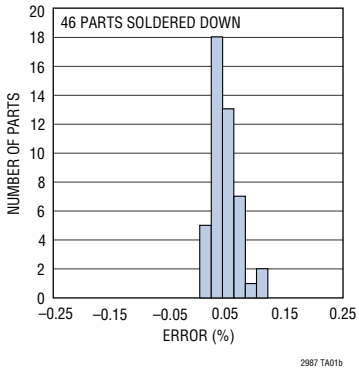
The LTM®2987 is a 16-channel µModule® (micromodule) Power System Manager used to sequence, trim (servo), margin, supervise, manage faults, provide telemetry and create fault logs. PMBus commands support power supply sequencing, precision point-of-load voltage adjustment and margining. DACs use a proprietary soft-connect algorithm to minimize supply disturbances. Supervisory functions include overvoltage and undervoltage threshold limits for sixteen power supply output channels and two power supply input channels, as well as over and under temperature limits. Programmable fault responses can disable the power supplies with optional retry after a fault is detected. Faults that disable a power supply can automatically trigger black box EEPROM storage of fault status and associated telemetry. An internal 16-bit ADC monitors sixteen output voltages, two input voltages, and die temperature. In addition, odd numbered channels can be configured to measure the voltage across a current sense resistor. A programmable watchdog timer monitors microprocessor activity for a stalled condition and resets the microprocessor if necessary. A single wire bus synchronizes power supplies across multiple LTC Power System Management (PSM) devices. Configuration EEPROM with ECC supports autonomous operation without additional software.

TYPICAL APPLICATION

16-Channel PMBus Power System Manager



Power Supply Accuracy



Rev B

ABSOLUTE MAXIMUM RATINGS

(Notes 1, 2, 3)

Supply Voltages:
- V_{PWR} ..... –0.3V to 15V
- V_{IN_SNS} ..... –0.3V to 15V
- V_{DD33} ..... –0.3V to 3.6V
- V_{DD25} ..... –0.3V to 2.75V

Digital Input/Output Voltages:
- ALERTB, SDA, SCL, CONTROL0, CONTROL1 ..... –0.3V to 5.5V
- PWRGD, SHARE_CLK, WDI/RESETB, WP ..... –0.3V to V_{DD33} + 0.3V
- FAULTB00, FAULTB01, FAULTB10, FAULTB11 ..... –0.3V to V_{DD33} + 0.3V
- ASEL0, ASEL1 ..... –0.3V to V_{DD33} + 0.3V

Analog Voltages:
- REFP ..... –0.3V to 1.35V
- REFM ..... –0.3V to 0.3V
- $V_{SENSEP[7:0]}$ ..... –0.3V to 6V
- $V_{SENSEM[7:0]}$ ..... –0.3V to 6V
- $V_{OUT\_EN[3:0]}$, V_{IN_EN} ..... –0.3V to 15V
- $V_{OUT\_EN[7:4]}$ ..... –0.3V to 6V
- $V_{DACP[7:0]}$ ..... –0.3V to 6V
- $V_{DACM[7:0]}$ ..... –0.3V to 0.3V

Pull-Up Resistors:
- V_{PU} ..... –0.3V to 5.5V
- R_{PU1}, R_{PU2}, R_{PU3}, R_{PU4} ..... –0.3V to 5.5V

Operating Junction Temperature Range:
- LTM2987C ..... 0°C to 70°C
- LTM2987I ..... –40°C to 105°C

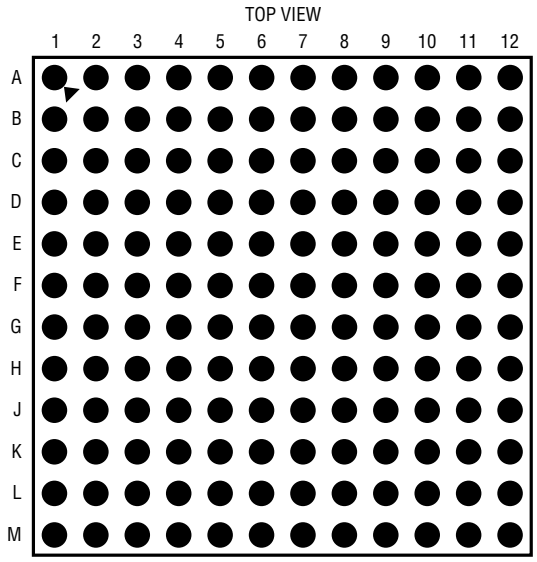
Storage Temperature Range ..... –55°C to 125°C*

Maximum Junction Temperature ..... 125°C*

Maximum Solder Temperature ..... 250°C

*See OPERATION section of the LTC2977 data sheet for detailed EEPROM derating information for junction temperatures in excess of 105°C.

PIN CONFIGURATION



BGA PACKAGE
144-LEAD (15mm × 15mm × 3.42mm)

T_{JMAX} = 125°C, θ_{JA} = 25.2°C/W, θ_{JCtop} = 15.6°C/W, $\theta_{JCbottom}$ = 7.1°C/W, θ_{JB} = 10.4°C/W, WEIGHT = 1.6g, VALUES DETERMINED PER JEDEC 51-9, 51-12

ORDER INFORMATION

PART NUMBER	PAD OR BALL FINISH	PART MARKING*		PACKAGE TYPE	MSL RATING	OPERATING JUNCTION TEMPERATURE RANGE
		DEVICE	FINISH CODE			
LTM2987CY#PBF	SAC305 (RoHS)	LTM2987Y	e1	BGA	3	0°C to 70°C
LTM2987IY#PBF	SAC305 (RoHS)	LTM2987Y	e1	BGA	3	–40°C to 105°C

- Contact the factory for parts specified with wider operating temperature ranges. *Pad or ball finish code is per IPC/JEDEC J-STD-609.
- Recommended LGA and BGA PCB Assembly and Manufacturing Procedures
- LGA and BGA Package and Tray Drawings

ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the full operating temperature range, otherwise specifications are at T_J = 25°C. V_{PWR} = V_{IN_SNS} = 12V, V_{DD33}, REFP and REFM pins floating, unless otherwise indicated. (Notes 2, 3)

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
Power Supply Characteristics							
V_{PWR}	V_{PWR} Supply Input Operating Range		●	4.5		15	V
I_{PWR}	V_{PWR} Supply Current	4.5V ≤ V_{PWR} ≤ 15V, V_{DD33} Floating	●		10	13	mA
I_{VDD33}	V_{DD33} Supply Current	3.13V ≤ V_{DD33} ≤ 3.47V, V_{PWR} = V_{DD33}	●		10	13	mA
V_{UVLO_VDD33}	V_{DD33} Undervoltage Lockout	V_{DD33} Ramping Up, V_{PWR} = V_{DD33}	●	2.35	2.55	2.8	V
	V_{DD33} Undervoltage Lockout Hysteresis				120		mV
V_{DD33}	Supply Input Operating Range	V_{PWR} = V_{DD33}	●	3.13		3.47	V
	Regulator Output Voltage	4.5V ≤ V_{PWR} ≤ 15V	●	3.13	3.26	3.47	V
	Regulator Output Short-Circuit Current	V_{PWR} = 4.5V, V_{DD33} = 0V	●	75	90	140	mA
V_{DD25}	Regulator Output Voltage	3.13V ≤ V_{DD33} ≤ 3.47V	●	2.35	2.5	2.6	V
	Regulator Output Short-Circuit Current	V_{PWR} = V_{DD33} = 3.47V, V_{DD25} = 0V	●	30	55	80	mA
t_{INIT}	Initialization Time	Time from V_{IN} Applied Until the TON_DELAY Timer Starts			30		ms
Voltage Reference Characteristics							
V_{REF}	Output Voltage	(Note 4)			1.232		V
	Temperature Coefficient				3		ppm/°C
	Hysteresis	(Note 5)			100		ppm
ADC Characteristics							
V_{IN_ADC}	Voltage Sense Input Range	Differential Voltage: V_{IN_ADC} = ($V_{SENSEPn}$ – $V_{SENSEMn}$)	●	0		6	V
		Single-Ended Voltage: $V_{SENSEMn}$	●	–0.1		0.1	V
	Current Sense Input Range (Odd Numbered Channels Only)	Single-Ended Voltage: $V_{SENSEPn}$, $V_{SENSEMn}$	●	–0.1		6	V
		Differential Voltage: V_{IN_ADC}	●	–170		170	mV
N_ADC	Voltage Sense Resolution (Uses L16 Format)	0V ≤ V_{IN_ADC} ≤ 6V Mfr_config_adc_hires = 0			122		µV/LSB
	Current Sense Resolution (Odd Numbered Channels Only)	0mV ≤ |V_{IN_ADC}| < 16mV (Note 6) 16mV ≤ |V_{IN_ADC}| < 32mV 32mV ≤ |V_{IN_ADC}| < 63.9mV 63.9mV ≤ |V_{IN_ADC}| < 127.9mV 127.9mV ≤ |V_{IN_ADC}| Mfr_config_adc_hires = 1			15.625 31.25 62.5 125 250		µV/LSB µV/LSB µV/LSB µV/LSB µV/LSB
TUE_ADC_VOLT_SNS	Total Unadjusted Error (Note 4)	Voltage Sense Mode V_{IN_ADC} ≥ 1V	●			±0.25	% of Reading
		Voltage Sense Mode 0 ≤ V_{IN_ADC} ≤ 1V	●			±2.5	mV
TUE_ADC_CURR_SNS	Total Unadjusted Error (Note 4)	Current Sense Mode, Odd Numbered Channels Only, 20mV ≤ V_{IN_ADC} ≤ 170mV	●			±0.7	% of Reading
		Current Sense Mode, Odd Numbered Channels Only, V_{IN_ADC} ≤ 20mV	●			±140	µV
V_{OS_ADC}	Offset Error	Current Sense Mode, Odd Numbered Channels Only	●			±100	µV
t_{CONV_ADC}	Conversion Time	Voltage Sense Mode (Note 7)			6.15		ms
		Current Sense Mode (Note 7)			24.6		ms
		Temperature Input (Note 7)			24.6		ms

ELECTRICAL CHARACTERISTICS

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SYMBOL	PARAMETER	CONDITIONS			MIN	TYP	MAX	UNITS
t_{UPDATE_ADC}	Update Time	Odd Numbered Channels in Current Sense Mode (Note 7)				160		ms
C_{IN_ADC}	Input Sampling Capacitance					1		pF
f_{IN_ADC}	Input Sampling Frequency					62.5		kHz
I_{IN_ADC}	Input Leakage Current	V_{IN_ADC} = 0V, 0V ≤ $V_{COMMONMODE}$ ≤ 6V, Current Sense Mode		●			±0.5	µA
	Differential Input Current	V_{IN_ADC} = 0.17V, Current Sense Mode		●		80	250	nA
		V_{IN_ADC} = 6V, Voltage Sense Mode		●		10	15	µA
DAC Output Characteristics								
N_V_{DACP}	Resolution					10		Bits
V_{FS_VDACP}	Full-Scale Output Voltage (Programmable)	DAC Code = 0x3FF DAC Polarity = 1	Buffer Gain Setting_0 Buffer Gain Setting_1	● ●	1.29 2.48	1.38 2.65	1.44 2.77	V V
INL_V_{DACP}	Integral Nonlinearity	(Note 8)					±2	LSB
DNL_V_{DACP}	Differential Nonlinearity	(Note 8)		●			±2.4	LSB
V_{OS_VDACP}	Offset Voltage	(Note 8)		●			±10	mV
V_{DACP}	Load Regulation (V_{DACPn} – V_{DACMn})	V_{DACPn} = 2.65V, I_{VDACPn} Sourcing = 2mA				100		ppm/mA
		V_{DACPn} = 0.1V, I_{VDACPn} Sinking = 2mA				100		ppm/mA
	PSRR (V_{DACPn} – V_{DACMn})	DC: 3.13V ≤ V_{DD33} ≤ 3.47V, V_{PWR} = V_{DD33}				60		dB
		100mV Step in 20ns with 50pF Load				40		dB
	DC CMRR (V_{DACPn} – V_{DACMn})	–0.1V ≤ V_{DACMn} ≤ 0.1V				60		dB
	Leakage Current	V_{DACPn} Hi-Z, 0V ≤ V_{DACPn} ≤ 6V		●			±100	nA
	Short-Circuit Current Low	V_{DACPn} Shorted to GND		●	–10		–4	mA
	Short-Circuit Current High	V_{DACPn} Shorted to V_{DD33}		●	4		10	mA
C_{OUT}	Output Capacitance	V_{DACPn} Hi-Z				10		pF
t_{S_VDACP}	DAC Output Update Rate	Fast Servo Mode				500		µs
DAC Soft-Connect Comparator Characteristics								
V_{OS_CMP}	Offset Voltage	V_{DACPn} = 0.2V		●		±1	±18	mV
		V_{DACPn} = 1.3V		●		±2	±26	mV
		V_{DACPn} = 2.65V		●		±3	±52	mV
Voltage Supervisor Characteristics								
V_{IN_VS}	Input Voltage Range (Programmable)	V_{IN_VS} = ($V_{SENSEPn}$ – $V_{SENSEMn}$)	Low Resolution Mode High Resolution Mode	● ●	0 0		6 3.8	V V
		Single-Ended Voltage: $V_{SENSEMn}$		●	–0.1		0.1	V
N_VS	Voltage Sensing Resolution	0V to 3.8V Range: High Resolution Mode				4		mV/LSB
		0V to 6V Range: Low Resolution Mode				8		mV/LSB
TUE_VS	Total Unadjusted Error	2V ≤ V_{IN_VS} ≤ 6V, Low Resolution Mode		●			±1.25	% of Reading
		1.5V < V_{IN_VS} ≤ 3.8V, High Resolution Mode		●			±1.0	% of Reading
		0.8V ≤ V_{IN_VS} ≤ 1.5V, High Resolution Mode		●			±1.5	% of Reading
t_{S_VS}	Update Period					12.21		µs

ELECTRICAL CHARACTERISTICS

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SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V_{IN_SNS} Input Characteristics							
V_{VIN_SNS}	V_{IN_SNS} Input Voltage Range		●	0		15	V
R_{VIN_SNS}	V_{IN_SNS} Input Resistance		●	70	90	110	kΩ
TUE_{VIN_SNS}	VIN_ON, VIN_OFF Threshold Total Unadjusted Error	3V ≤ V_{VIN_SNS} ≤ 8V	●			±2.0	% of Reading
		V_{VIN_SNS} > 8V	●			±1.0	% of Reading
	READ_VIN Total Unadjusted Error	3V ≤ V_{VIN_SNS} ≤ 8V	●			±1.5	% of Reading
		V_{VIN_SNS} > 8V	●			±1.0	% of Reading
Temperature Sensor Characteristics							
TUE_TS	Total Unadjusted Error				±1		°C
V_{OUT} Enable Output (V_{OUT_EN} [3:0]) Characteristics							
V_{VOUT_ENn}	Output High Voltage (Note 9)	I_{VOUT_ENn} = –5µA, V_{DD33} = 3.3V	●	10	12.5	14.7	V
I_{VOUT_ENn}	Output Sourcing Current	V_{VOUT_ENn} Pull-Up Enabled, V_{VOUT_ENn} = 1V	●	–5	–6	–8	µA
	Output Sinking Current	Strong Pull-Down Enabled, V_{VOUT_ENn} = 0.4V	●	3	5	8	mA
		Weak Pull-Down Enabled, V_{VOUT_ENn} = 0.4V	●	28	43	60	µA
	Output Leakage Current	Internal Pull-Up Disabled, 0V ≤ V_{VOUT_ENn} ≤ 15V	●			±1	µA
V_{OUT} Enable Output (V_{OUT_EN} [7:4]) Characteristics							
I_{VOUT_ENn}	Output Sinking Current	Strong Pull-Down Enabled, V_{OUT_ENn} = 0.1V			6		mA
	Output Leakage Current	0V ≤ V_{VOUT_ENn} ≤ 6V	●			±1	µA
V_{IN} Enable Output (V_{IN_EN}) Characteristics							
V_{VIN_EN}	Output High Voltage	I_{VIN_EN} = –5µA, V_{DD33} = 3.3V	●	10	12.5	14.7	V
I_{VIN_EN}	Output Sourcing Current	V_{IN_EN} Pull-Up Enabled, V_{VIN_EN} = 1V	●	–5	–6	–8	µA
	Output Sinking Current	V_{VIN_EN} = 0.4V	●	3	5	8	mA
	Leakage Current	Internal Pull-Up Disabled, 0V ≤ V_{VIN_EN} ≤ 15V	●			±1	µA
EEPROM Characteristics							
Endurance	(Notes 10, 11)	0°C < T_J < 85°C During EEPROM Write Operations	●	10,000			Cycles
Retention	(Notes 10, 11)	T_J < 105°C	●	20			Years
t_{MASS_WRITE}	Mass Write Operation Time (Note 12)	STORE_USER_ALL, 0°C < T_J < 85°C During EEPROM Write Operations	●		440	4100	ms
General Purpose Pull-Up Resistors							
R_{PU}	Pull-Up Resistance				10		kΩ
Digital Inputs SCL, SDA, CONTROL0, CONTROL1, WDI/RESETB, FAULTB00, FAULTB01, FAULTB10, FAULTB11, WP							
V_{IH}	High Level Input Voltage		●	2.1			V
V_{IL}	Low Level Input Voltage		●			1.5	V
V_{HYST}	Input Hysteresis				20		mV

ELECTRICAL CHARACTERISTICS

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SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
I_{LEAK}	Input Leakage Current	0V ≤ V_{PIN} ≤ 5.5V, SDA, SCL, CONTROL*n* Pins Only	●			±2	µA
		0V ≤ V_{PIN} ≤ V_{DD33} + 0.3V, FAULTB*zn*, WDI/RESETB, WP Pins Only	●			±2	µA
t_{SP}	Pulse Width of Spike Suppressed	FAULTB*zn*, CONTROL*n* Pins Only			10		µs
		SDA, SCL Pins Only			98		ns
t_{FAULT_MIN}	Minimum Low Pulse Width for Externally Generated Faults			110			ms
t_{RESETB}	Pulse Width to Assert Reset	$V_{WDI/RESETB}$ ≤ 1.5V	●	300			µs
t_{WDI}	Pulse Width to Reset Watchdog Timer	$V_{WDI/RESETB}$ ≤ 1.5V	●	0.3		200	µs
f_{WDI}	Watchdog Interrupt Input Frequency		●			1	MHz
C_{IN}	Digital Input Capacitance				10		pF
Digital Input SHARE_CLK							
V_{IH}	High Level Input Voltage		●	1.6			V
V_{IL}	Low Level Input Voltage		●			0.8	V
$f_{SHARE\_CLK\_IN}$	Input Frequency Operating Range		●	90		110	kHz
t_{LOW}	Assertion Low Time	V_{SHARE_CLK} < 0.8V	●	0.825		1.1	µs
t_{RISE}	Rise Time	V_{SHARE_CLK} < 0.8V to V_{SHARE_CLK} > 1.6V	●			450	ns
I_{LEAK}	Input Leakage Current	0V ≤ V_{SHARE_CLK} ≤ V_{DD33} + 0.3V	●			±1	µA
C_{IN}	Input Capacitance				10		pF
Digital Outputs SDA, ALERTB, PWRGD, SHARE_CLK, FAULTB00, FAULTB01, FAULTB10, FAULTB11							
V_{OL}	Digital Output Low Voltage	I_{SINK} = 3mA	●			0.4	V
$f_{SHARE\_CLK\_OUT}$	Output Frequency Operating Range	5.49kΩ Pull-Up to V_{DD33}	●	90	100	110	kHz
Digital Inputs ASEL0,ASEL1							
V_{IH}	Input High Threshold Voltage		●	V_{DD33} – 0.5			V
V_{IL}	Input Low Threshold Voltage		●			0.5	V
I_{IH}, I_{IL}	High, Low Input Current	ASEL[1:0] = 0, V_{DD33}	●			±95	µA
I_{HIZ}	Hi-Z Input Current		●			±24	µA
C_{IN}	Input Capacitance				10		pF
Serial Bus Timing Characteristics							
f_{SCL}	Serial Clock Frequency (Note 13)		●	10		400	kHz
t_{LOW}	Serial Clock Low Period (Note 13)		●	1.3			µs
t_{HIGH}	Serial Clock High Period (Note 13)		●	0.6			µs
t_{BUF}	Bus Free Time Between Stop and Start (Note 13)		●	1.3			µs
$t_{HD,STA}$	Start Condition Hold Time (Note 13)		●	600			ns
$t_{SU,STA}$	Start Condition Setup Time (Note 13)		●	600			ns
$t_{SU,STO}$	Stop Condition Setup Time (Note 13)		●	600			ns
$t_{HD,DAT}$	Data Hold Time (LTM2987 Receiving Data) (Note 13)		●	0			ns
	Data Hold Time (LTM2987 Transmitting Data) (Note 13)		●	300		900	ns

ELECTRICAL CHARACTERISTICS

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SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
$t_{SU,DAT}$	Data Setup Time (Note 13)		●	100			ns
t_{SP}	Pulse Width of Spike Suppressed (Note 13)				98		ns
$t_{TIMEOUT\_BUS}$	Time Allowed to Complete any PMBus Command After Which Time SDA Will Be Released and Command Terminated	Mfr_config_all_longer_pmbus_timeout = 0 Mfr_config_all_longer_pmbus_timeout = 1	● ●		25 200	35 280	ms ms
Additional Digital Timing Characteristics							
t_{OFF_MIN}	Minimum Off Time for Any Channel				100		ms

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating for extended periods may affect device reliability and lifetime.

Note 2: All currents into device pins are positive. All currents out of device pins are negative. All voltages are referenced to GND unless otherwise specified. If power is supplied to the chip via the V_{DD33} pin only, connect V_{PWR} and V_{DD33} pins together.

Note 3: The LTM2987 electrical characteristics apply to each half of the device, unless otherwise noted. The specifications and functions are the same for both Device A pins and Device B pins.

Note 4: The ADC total unadjusted error includes all error sources. First, a two-point analog trim is performed to achieve a flat reference voltage (V_{REF}) over temperature. This results in minimal temperature coefficient, but the absolute voltage can still vary. To compensate for this, a high-resolution, drift-free, and noiseless digital trim is applied at the output of the ADC, resulting in a very high accuracy measurement.

Note 5: Hysteresis in the output voltage is created by package stress that differs depending on whether the module was previously at a higher or lower temperature. Output voltage is always measured at 25°C, but the module is cycled to 105°C or –40°C before successive measurements. Hysteresis is roughly proportional to the square of the temperature change.

Note 6: The current sense resolution is determined by the L11 format and the mV units of the returned value. For example a full scale value of 170mV returns a L11 value of 0xF2A8 = 680 • 2^{-2} = 170. This is the lowest range that can represent this value without overflowing the L11 mantissa and the resolution for 1LSB in this range is 2^{-2} mV = 250µV. Each successively lower range improves resolution by cutting the LSB size in half.

Note 7: The time between successive ADC conversions (latency of the ADC) for any given channel is given as: 36.9ms + (6.15ms • number of ADC channels configured in Low Resolution mode) + (24.6ms • number of ADC channels configured in High Resolution mode).

Note 8: Nonlinearity is defined from the first code that is greater than or equal to the maximum offset specification to full-scale code, 1023.

Note 9: Output enable pins are charge pumped from V_{DD33}.

Note 10: EEPROM endurance and retention are guaranteed by design, characterization and correlation with statistical process controls. The minimum retention specification applies for devices whose EEPROM has been cycled less than the minimum endurance specification.

Note 11: EEPROM endurance and retention will be degraded when T_J > 105°C.

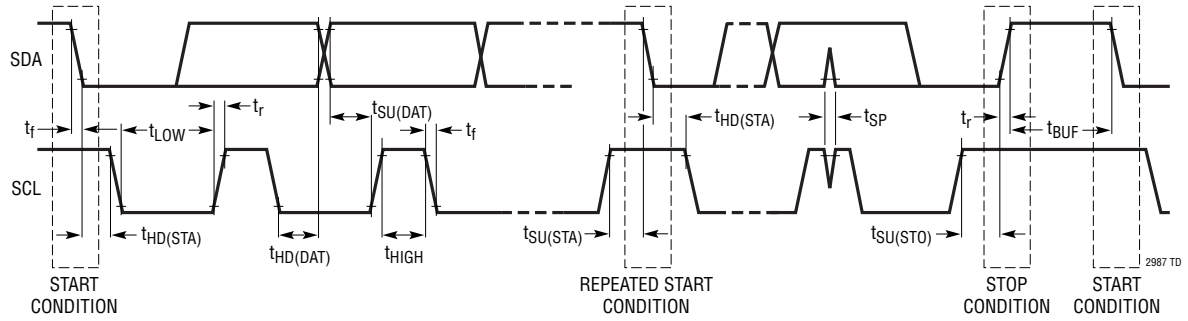
Note 12: The LTM2987 will not acknowledge any PMBus commands while a mass write operation is being executed. This includes the STORE_USER_ALL and MFR_FAULT_LOG_STORE commands or a fault log store initiated by a channel faulting off.

Note 13: Maximum capacitive load, C_B, for SCL and SDA is 400pF. Data and clock rise time (t_r) and fall time (t_f) are:

(20 + 0.1 • C_B) (ns) < t_r < 300ns and (20 + 0.1 • C_B) (ns) < t_f < 300ns.

C_B = capacitance of one bus line in pF. SCL and SDA external pull-up voltage, V_{IO}, is 3.13V < V_{IO} < 5.5V.

PMBUS TIMING DIAGRAM



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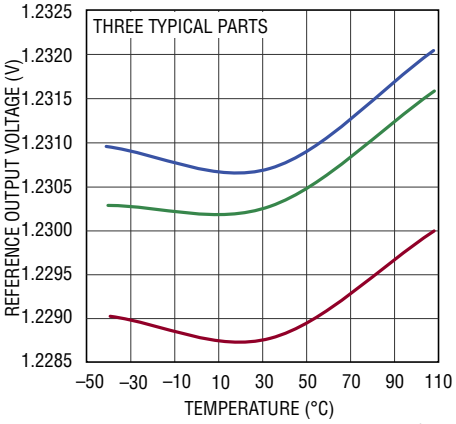
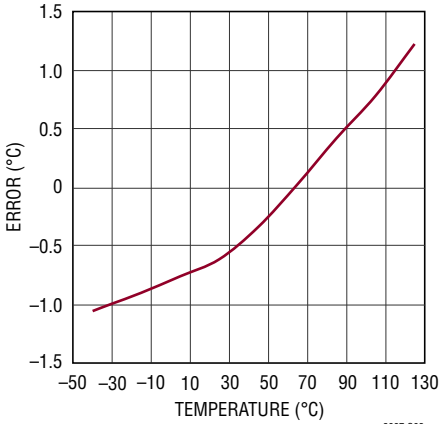
TYPICAL PERFORMANCE CHARACTERISTICS

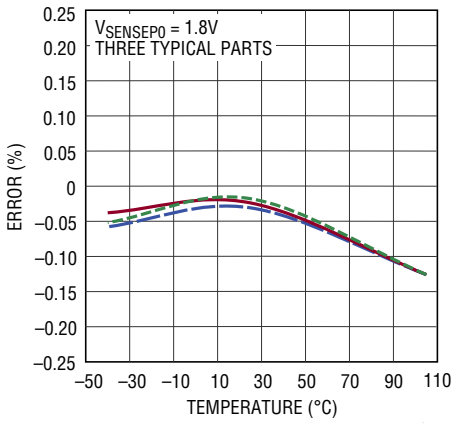
Reference Voltage vs Temperature



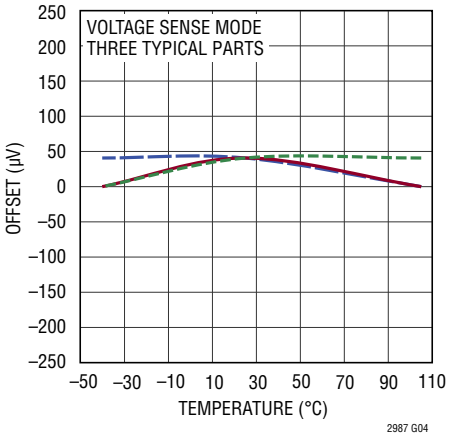
Temperature Sensor Error vs Temperature



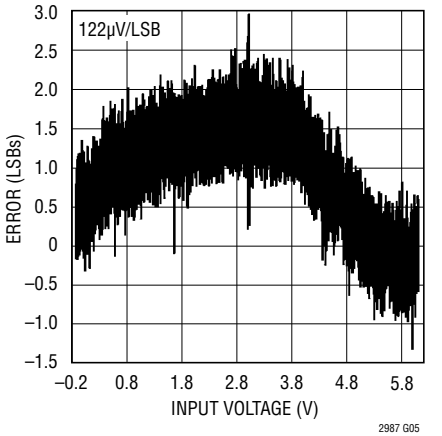
ADC Total Unadjusted Error vs Temperature



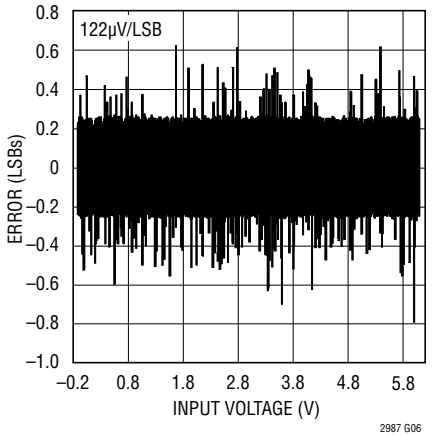
ADC Zero Code Center Offset Voltage vs Temperature



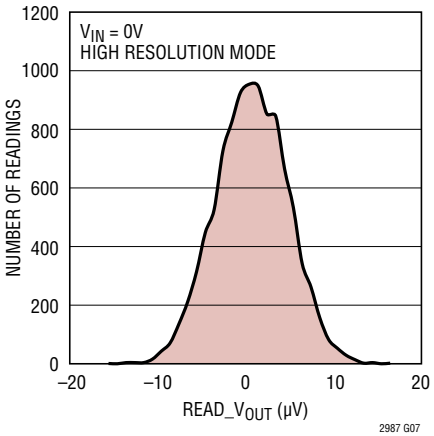
ADC INL



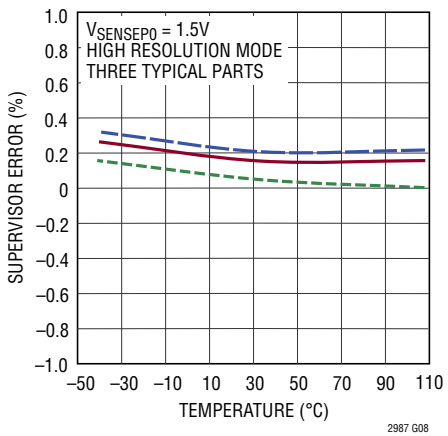
ADC DNL



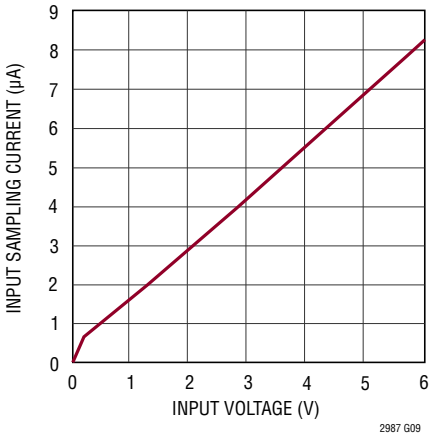
ADC Noise Histogram



Voltage Supervisor Total Unadjusted Error vs Temperature

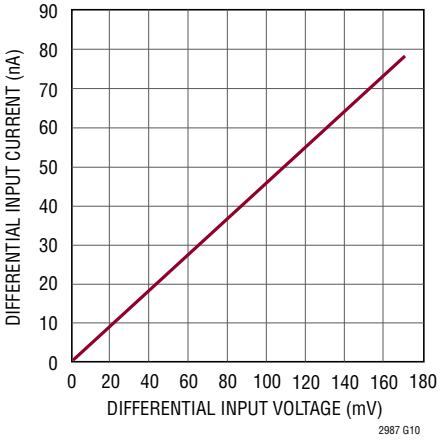


Input Sampling Current vs Differential Input Voltage

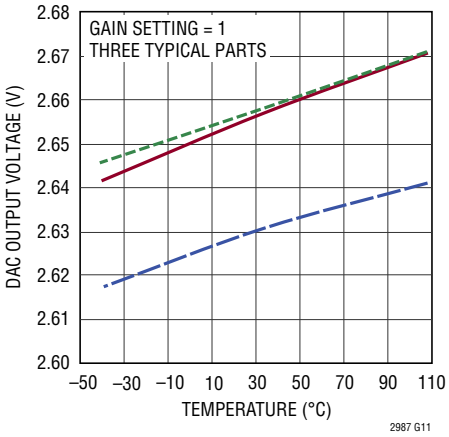


TYPICAL PERFORMANCE CHARACTERISTICS

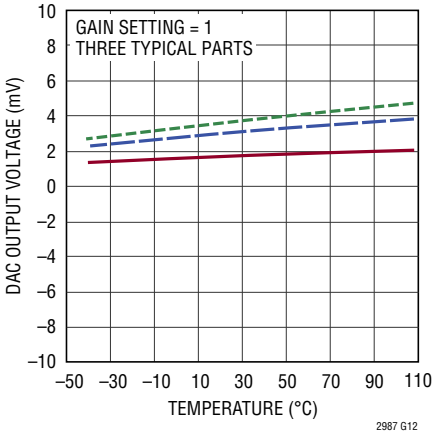
ADC High Resolution Mode Differential Input Current



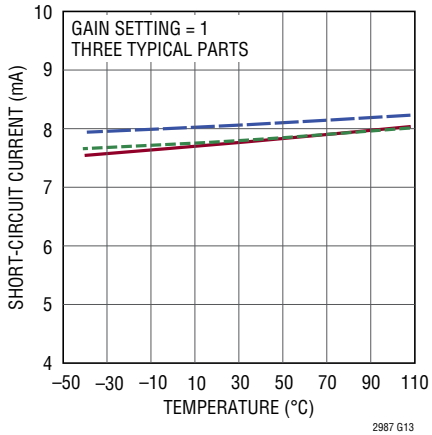
DAC Full-Scale Output Voltage vs Temperature



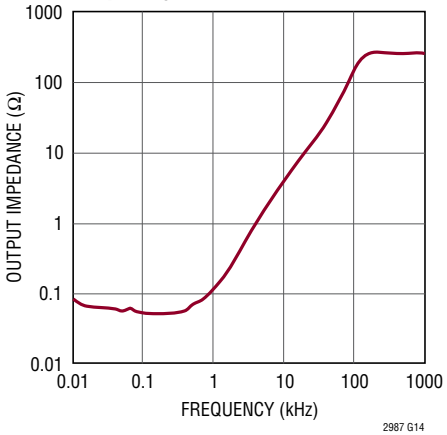
DAC Offset Voltage vs Temperature



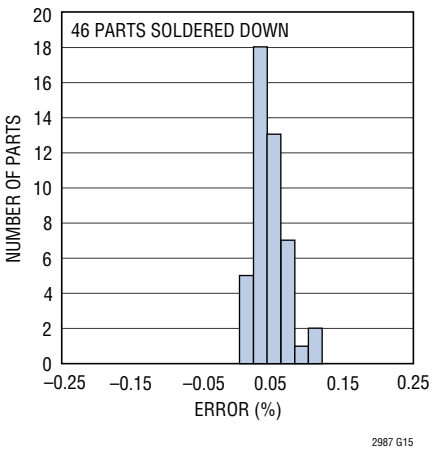
DAC Short-Circuit Current vs Temperature



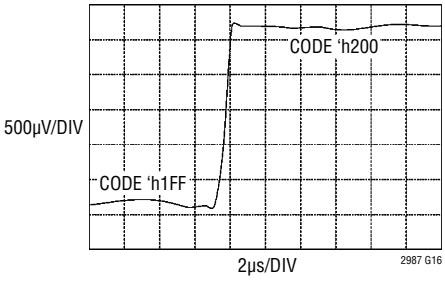
DAC Output Impedance vs Frequency



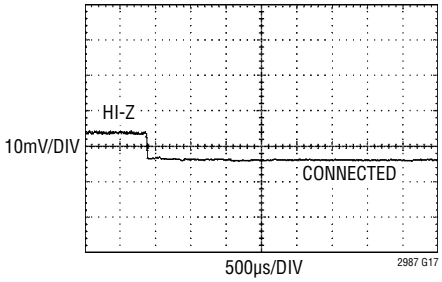
Closed-Loop Servo Error



DAC Transient Response to 1LSB DAC Code Change

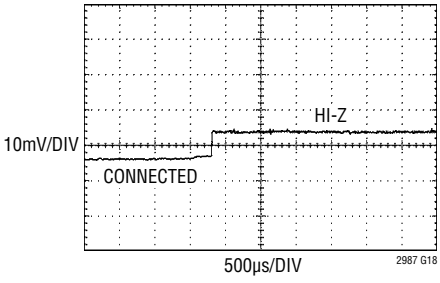


DAC Soft-Connect Transient Response When Transitioning from Hi-Z State to ON State



100k SERIES RESISTANCE ON
CODE: 'h1FF

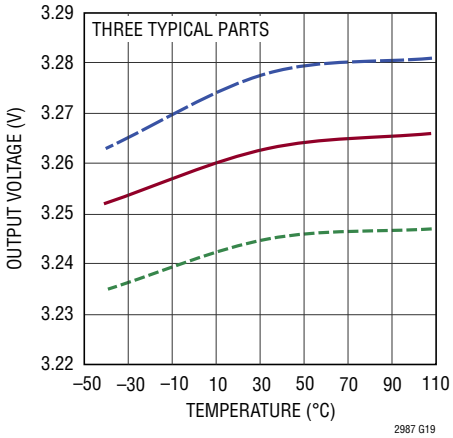
DAC Soft-Connect Transient Response When Transitioning from ON State to Hi-Z State



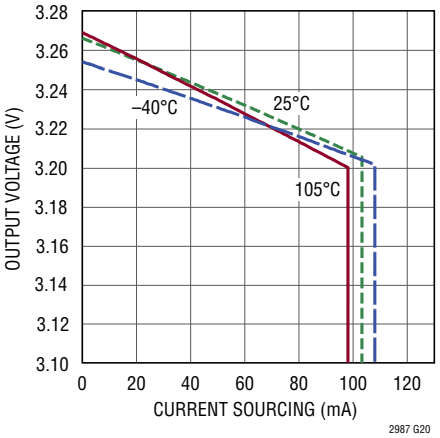
100k SERIES RESISTANCE ON
CODE: 'h1FF

TYPICAL PERFORMANCE CHARACTERISTICS

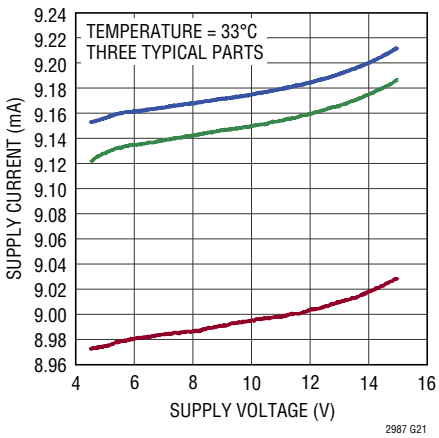
V_{DD33} Regulator Output Voltage vs Temperature



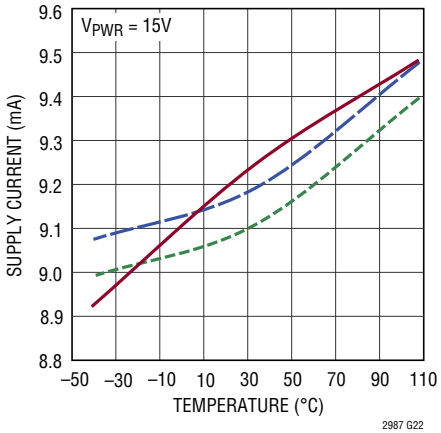
V_{DD33} Regulator Load Regulation



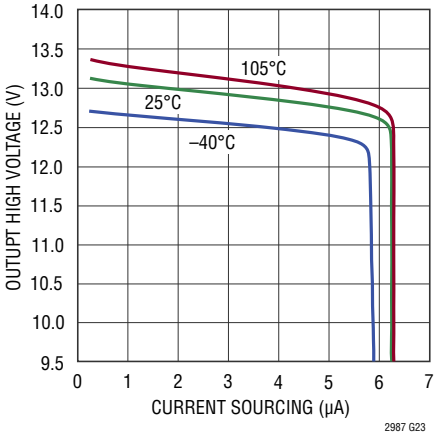
Supply Current vs Supply Voltage (1/2 LTM2987)



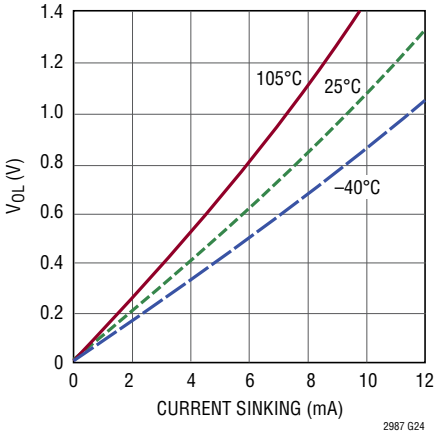
Supply Current vs Temperature (1/2 LTM2987)



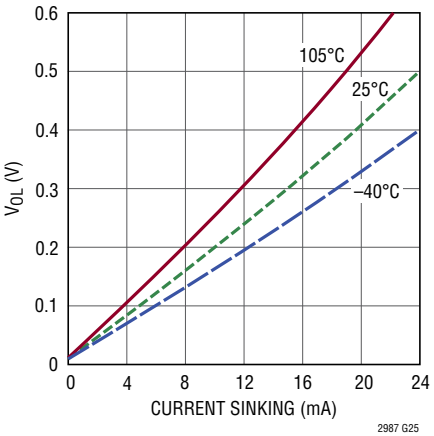
$V_{OUT\_EN[3:0]}$ and V_{IN_EN} Output High Voltage vs Current



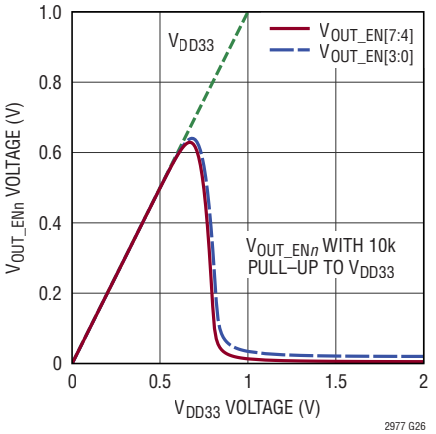
$V_{OUT\_EN[3:0]}$ and V_{IN_EN} Output V_{OL} vs Current



$V_{OUT\_EN[7:4]}$ V_{OL} vs Current



$V_{OUT\_EN[7:0]}$ Output Voltage vs V_{DD33}



PIN FUNCTIONS

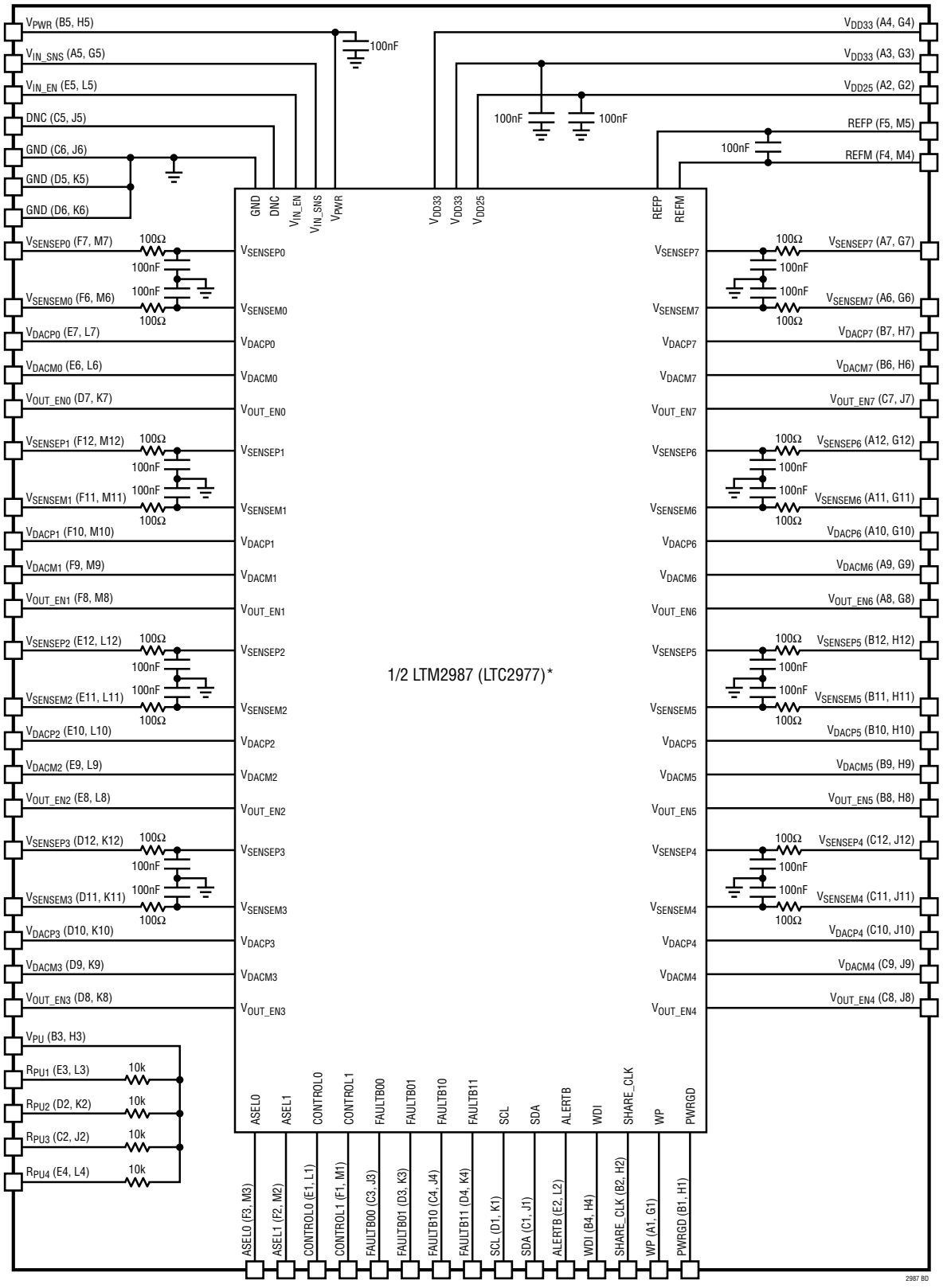
PIN NAME	PIN Device A	PIN Device B	PIN TYPE	DESCRIPTION
$V_{SENSEP0}$	F7*	M7*	In	DC/DC Converter Differential (+) Output Voltage-0 Sensing Pin
$V_{SENSEM0}$	F6*	M6*	In	DC/DC Converter Differential (–) Output Voltage-0 Sensing Pin
$V_{SENSEP1}$	F12*	M12*	In	DC/DC Converter Differential (+) Output Voltage or Current-1 Sensing Pins.
$V_{SENSEM1}$	F11*	M11*	In	DC/DC Converter Differential (–) Output Voltage or Current-1 Sensing Pins.
$V_{SENSEP2}$	E12*	L12*	In	DC/DC Converter Differential (+) Output Voltage-2 Sensing Pin
$V_{SENSEM2}$	E11*	L11*	In	DC/DC Converter Differential (–) Output Voltage-2 Sensing Pin
$V_{SENSEP3}$	D12*	K12*	In	DC/DC Converter Differential (+) Output Voltage or Current-3 Sensing Pins.
$V_{SENSEM3}$	D11*	K11*	In	DC/DC Converter Differential (–) Output Voltage or Current-3 Sensing Pins.
$V_{SENSEP4}$	C12*	J12*	In	DC/DC Converter Differential (+) Output Voltage-4 Sensing Pin
$V_{SENSEM4}$	C11*	J11*	In	DC/DC Converter Differential (–) Output Voltage-4 Sensing Pin
$V_{SENSEP5}$	B12*	H12*	In	DC/DC Converter Differential (+) Output Voltage or Current-5 Sensing Pins.
$V_{SENSEM5}$	B11*	H11*	In	DC/DC Converter Differential (–) Output Voltage or Current-5 Sensing Pins.
$V_{SENSEP6}$	A12*	G12*	In	DC/DC Converter Differential (+) Output Voltage-6 Sensing Pin
$V_{SENSEM6}$	A11*	G11*	In	DC/DC Converter Differential (–) Output Voltage-6 Sensing Pin
$V_{SENSEP7}$	A7*	G7*	In	DC/DC Converter Differential (+) Output Voltage or Current-7 Sensing Pin
$V_{SENSEM7}$	A6*	G6*	In	DC/DC Converter Differential (–) Output Voltage or Current-7 Sensing Pin
V_{OUT_EN0}	D7	K7	Out	DC/DC Converter Enable-0 Pin. Output High Voltage Optionally Pulled Up to 12V by 5µA
V_{OUT_EN1}	F8	M8	Out	DC/DC Converter Enable-1 Pin. Output High Voltage Optionally Pulled Up to 12V by 5µA
V_{OUT_EN2}	E8	L8	Out	DC/DC Converter Enable-2 Pin. Output High Voltage Optionally Pulled Up to 12V by 5µA
V_{OUT_EN3}	D8	K8	Out	DC/DC Converter Enable-3 Pin. Output High Voltage Optionally Pulled Up to 12V by 5µA
V_{OUT_EN4}	C8	J8	Out	DC/DC Converter Enable-4 Pin. Open-Drain Pull-Down Output.
V_{OUT_EN5}	B8	H8	Out	DC/DC Converter Enable-5 Pin. Open-Drain Pull-Down Output.
V_{OUT_EN6}	A8	G8	Out	DC/DC Converter Enable-6 Pin. Open-Drain Pull-Down Output.
V_{OUT_EN7}	C7	J7	Out	DC/DC Converter Enable-7 Pin. Open-Drain Pull-Down Output.
V_{IN_EN}	E5	L5	Out	DC/DC Converter V_{IN} ENABLE Pin. Output High Voltage Optionally Pulled Up to 12V by 5µA
V_{IN_SNS}	A5	G5	In	V_{IN} SENSE Input. This Voltage is Compared Against the V_{IN} On and Off Voltage Thresholds in Order to Determine When to Enable and Disable, Respectively, the Downstream DC/DC Converters
V_{PWR}	B5	H5	In	V_{PWR} Serves as the Unregulated Power Supply Input to the Chip (4.5V to 15V). If a 4.5V to 15V Supply Voltage is Unavailable, Short V_{PWR} to V_{DD33} and Power the Chip Directly from a 3.3V Supply
V_{DD33}	A4	G4	In/Out	If Shorted to V_{PWR}, it Serves as 3.13V to 3.47V Supply Input Pin. Otherwise it is a 3.3V Internally Regulated Voltage Output. If using the internal regulator to provide V_{DD33}, do not connect to V_{DD33} pins of any other devices
V_{DD33}	A3	G3	In	Input for Internal 2.5V Sub-Regulator. Short Pin A3 to Pin A4 and Pin G3 to Pin G4. If using the internal regulator to provide V_{DD33}, do not connect to V_{DD33} pins of any other devices
V_{DD25}	A2	G2	In/Out	2.5V Internally Regulated Voltage Output. Do not connect to V_{DD25} pins of any other devices
WP	A1	G1	In	Digital Input. Write-Protect Input Pin, Active High
PWRGD	B1	H1	Out	Power Good Open-Drain Output. Indicates When Outputs are Power Good. Can be Used as System Power-On Reset. The Latency of This Signal May Be as Long as the ADC Latency. See Note 6
SHARE_CLK	B2	H2	In/Out	Bidirectional Clock Sharing Pin. Connect a 5.49k Pull-Up Resistor to V_{DD33}. Connect to all other SHARE_CLK pins in the system
WDI/RESETB	B4	H4	In	Watchdog Timer Interrupt and Chip Reset Input. Connect a 10k Pull-Up Resistor to V_{DD33}. Rising Edge Resets Watchdog Counter. Holding This Pin Low for More Than t_{RESETB} Resets the Chip
FAULTB00	C3	J3	In/Out	Open-Drain Output and Digital Input. Active Low Bidirectional Fault Indicator-00. Connect a 10k Pull-Up Resistor to V_{DD33}
FAULTB01	D3	K3	In/Out	Open-Drain Output and Digital Input. Active Low Bidirectional Fault Indicator-01. Connect a 10k Pull-Up Resistor to V_{DD33}

PIN FUNCTIONS

PIN NAME	PIN Device A	PIN Device B	PIN TYPE	DESCRIPTION
FAULTB10	C4	J4	In/Out	Open-Drain Output and Digital Input. Active Low Bidirectional Fault Indicator-10. Connect a 10k Pull-Up Resistor to V_{DD33}
FAULTB11	D4	K4	In/Out	Open-Drain Output and Digital Input. Active Low Bidirectional Fault Indicator-11. Connect a 10k Pull-Up Resistor to V_{DD33}
SDA	C1	J1	In/Out	PMBus Bidirectional Serial Data Pin
SCL	D1	K1	In	PMBus Serial Clock Input Pin (400kHz Maximum)
ALERTB	E2	L2	Out	Open-Drain Output. Generates an Interrupt Request in a Fault/Warning Situation
CONTROL0	E1	L1	In	Control Pin 0 Input
CONTROL1	F1	M1	In	Control Pin 1 Input
ASEL0	F3	M3	In	Ternary Address Select Pin 0 Input. Connect to V_{DD33}, GND or Float to Encode 1 of 3 Logic States
ASEL1	F2	M2	In	Ternary Address Select Pin 1 Input. Connect to V_{DD33}, GND or Float to Encode 1 of 3 Logic States
REFP	F5	M5	Out	Reference Voltage Output
REFM	F4	M4	Out	Reference Return Pin
V_{DACP0}	E7	L7	Out	DAC0 Output
V_{DACM0}	E6*	L6*	Out	DAC0 Return. Connect to Channel 0 DC/DC Converter's GND Sense or Return to GND
V_{DACP1}	F10	M10	Out	DAC1 Output
V_{DACM1}	F9*	M9*	Out	DAC1 Return. Connect to Channel 1 DC/DC Converter's GND Sense or Return to GND
V_{DACP2}	E10	L10	Out	DAC2 Output
V_{DACM2}	E9*	L9*	Out	DAC2 Return. Connect to Channel 2 DC/DC Converter's GND Sense or Return to GND
V_{DACP3}	D10	K10	Out	DAC3 Output
V_{DACM3}	D9*	K9*	Out	DAC3 Return. Connect to Channel 3 DC/DC Converter's GND Sense or Return to GND
V_{DACP4}	C10	J10	Out	DAC4 Output
V_{DACM4}	C9*	J9*	Out	DAC4 Return. Connect to Channel 4 DC/DC Converter's GND Sense or Return to GND
V_{DACP5}	B10	H10	Out	DAC5 Output
V_{DACM5}	B9*	H9*	Out	DAC5 Return. Connect to Channel 5 DC/DC Converter's GND Sense or Return to GND
V_{DACP6}	A10	G10	Out	DAC6 Output
V_{DACM6}	A9*	G9*	Out	DAC6 Return. Connect to Channel 6 DC/DC Converter's GND Sense or Return to GND
V_{DACP7}	B7	H7	Out	DAC7 Output
V_{DACM7}	B6*	H6*	Out	DAC7 Return. Connect to Channel 7 DC/DC Converter's GND Sense or Return to GND
V_{PU}	B3	H3	In	Common Connection for Internal Pull-Up Resistors
R_{PU1}	E3	L3	Out	General Purpose 10k Pull-Up Resistor 1
R_{PU2}	D2	K2	Out	General Purpose 10k Pull-Up Resistor 2
R_{PU3}	C2	J2	Out	General Purpose 10k Pull-Up Resistor 3
R_{PU4}	E4	L4	Out	General Purpose 10k Pull-Up Resistor 4
GND	C6, D5, D6	J6, K5, K6	Ground	Device A Ground Pins are Isolated from the Device B Ground Pins
DNC	C5	J5	Do Not Connect	Do Not Connect to This Pin

*Any unused $V_{SENSEPn}$ or $V_{SENSEMn}$ or V_{DACMn} pins must be tied to GND.

BLOCK DIAGRAM



*NOTES: 1. ONLY 1/2 OF THE LTM2987 MODULE SHOWN
2. THE TWO 8-CHANNEL LTC2977 HALVES ARE IDENTICAL AND COMPLETELY ISOLATED
3. PIN NAMES REFER TO (DEVICE A, DEVICE B)

OPERATION

Overview

The LTM2987 contains two independent LTC2977 devices and most of the passive components required to make a complete 16-channel power system manager. The LTM2987 simplifies power system design by integrating the required passive components, reducing the bill-of-materials and improving PC board routing efficiency.

Each half of the LTM2987 behaves the same as a standalone LTC2977 including independent power supply and ground pins. This feature can be used to increase redundancy in a system while keeping the overall solution size small.

Refer to the LTC2977 data sheet for a detailed description of the device operation, the PMBus command set, and Applications Information.

Device Address

Since the LTM2987 consists of two independent LTC2977 devices, each half of the LTM2987 must be configured for a unique address. The I^2C/SMBus addresses of the LTM2987 are configured in the same manner as for individual LTC2977 devices. The LTM2987 also responds to the LTC2977 global address and the SMBus Alert Response address, regardless of the state of the ASEL pins and the MFR_I2C_BASE_ADDRESS register. Please refer to the Device Address section in the LTC2977 data sheet for more details.

MFR_SPECIAL_ID

The LTM2987 contains unique MFR_SPECIAL_ID values to differentiate it from the LTC2977. Table 1 lists the MFR_SPECIAL_ID values for the LTM2987.

Table 1. LTM2987 MFR_SPECIAL_ID Values

LTM2987 DEVICE	MFR_SPECIAL_ID
Device A	0x8011
Device B	0x8021

APPLICATIONS INFORMATION

OVERVIEW

The LTM2987 is a Power System Manager that is capable of sequencing, margining, trimming, supervising output voltage for OV/UV conditions, providing fault management, and voltage readback for sixteen DC/DC converters. Input voltage and LTM2987 junction temperature readback are also available. Odd numbered channels can be configured to read back current sense resistor voltages. Multiple LTM2987s can be synchronized to operate in unison using the SHARE_CLK, FAULTB and CONTROL pins. The LTM2987 utilizes a PMBus compliant interface and command set.

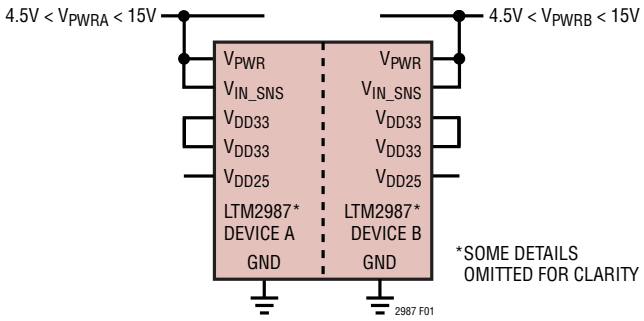


Figure 1. Powering LTM2987 Directly from an Intermediate Bus

POWERING THE LTM2987

The LTM2987 can be powered two ways. The first method requires that a voltage between 4.5V and 15V be applied to the V_{PWR} pin. See Figure 1. Internal linear regulators convert V_{PWR} down to 3.3V which drives all of the internal circuitry in each device. Do not tie the $V_{DD33(A)}$ and $V_{DD33(B)}$ pins together since each half of the LTM2987 has independent voltage regulators.

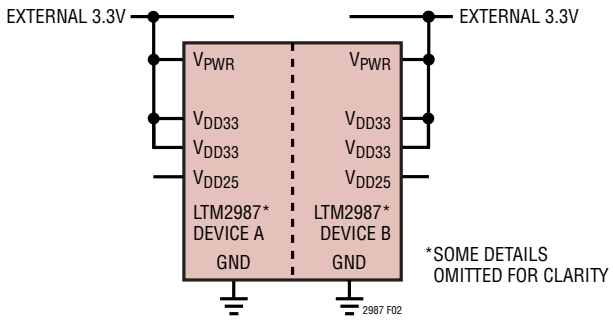


Figure 2. Powering LTM2987 from External 3.3V Supply

Alternatively, power from an external 3.3V supply may be applied directly to the V_{DD33} pins using a voltage between 3.13V and 3.47V. Tie V_{PWR} to the V_{DD33} pins. See Figure 2. In this case, $V_{DD33(A)}$ and $V_{DD33(B)}$ may be tied together. All functionality is available when using this alternate power method. The higher voltages needed for the $V_{OUT\_EN[0:3]}$ pins and bias for the V_{SENSE} pins are charge pumped from V_{DD33}.

The method used to power each device in the LTM2987 is independent of the other device. Either method may be used in any combination.

APPLICATION CIRCUITS

Undedicated Pull-Up Resistors

Each half of the LTM2987 module has four undedicated 10k pull-up resistors as shown in Figure 3. The common pull-up voltage is applied to the V_{PU} pin, and the individual pull-up resistors are on R_{PU1}, R_{PU2}, R_{PU3} and R_{PU4}. These pull-up resistors can be used for the open-drain pins such as SDA, SCL, ALERTB or FAULTB*zn* in which case the common pull-up voltage V_{PU} should be connected to a 3.3V supply. To simplify the layout, the pin V_{PU} is adjacent to the V_{DD33} pin.

Anti-Aliasing Filter Considerations

Since most of the passive components required for operation are integrated into the LTM2987, no external filter components are required.

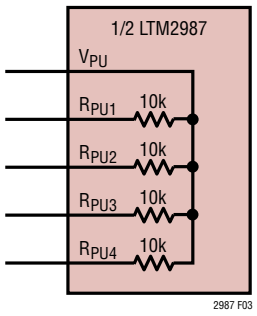


Figure 3. Undedicated Pull-Up Resistors

APPLICATIONS INFORMATION

V_{IN} Sense

Voltages other than V_{IN} can be monitored and supervised using the V_{IN_SNS} pins. Each V_{IN_SNS} pin has a calibrated internal divider allowing it to directly sense voltages up to 15V.

Unused ADC Sense Inputs

Connect all unused ADC sense inputs ($V_{SENSEP}n$ or $V_{SENSEM}n$) to GND. In a system where the inputs are connected to removable cards and may be left floating in certain situations, connect the inputs to GND using 100k resistors, as shown in Figure 4.

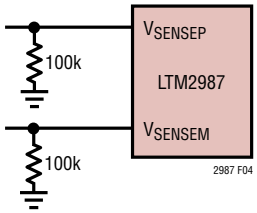


Figure 4. Connecting Unused Inputs to GND

PCB ASSEMBLY AND LAYOUT SUGGESTIONS

Bypass Capacitor Placement

All required bypass capacitors are integrated into the LTM2987. No additional bypass capacitance is required. The PCB layout should adhere to good layout guidelines. A multilayer PCB that dedicates a layer to power and ground is recommended. Low resistance and low inductance power and ground connections are important to minimize power supply noise and ensure proper device operation.

DESIGN CHECKLIST

I^2C

- Each half of the LTM2987 must be configured for a unique address. Unique hardware ASEL*n* values are recommended for simplest in system programming.
- The address select pins (ASEL*n*) are tri-level; Check Table 1 of the LTC2977 data sheet.
- Check addresses for collision with other devices on the bus and any global addresses.

Output Enables

- Use appropriate pull-up resistors on all $V_{OUT\_EN}n$ pins.
- Verify that the Absolute Maximum Ratings of the $V_{OUT\_EN}n$ pins are not exceeded.

V_{IN} Sense

- No external resistive divider is required to sense V_{IN}; V_{IN_SNS} already has an internal calibrated divider.

Logic Signals

- Verify the Absolute Maximum Ratings of the digital pins (SCL, SDA, ALERTB, FAULTB*zn*, CONTROL*n*, SHARE_CLK, WDI, ASEL*n*, PWRGD) are not exceeded.
- Connect all SHARE_CLK pins in the system together and pull up to 3.3V with a 5.49k resistor.
- Do not leave CONTROL*n* pins floating. Pull up to 3.3V with a 10k resistor.
- Tie WDI/RESETB to V_{DD33} with a 10k resistor. Do not connect a capacitor to the WDI/RESETB pin.
- Tie WP to either V_{DD33} or GND. Do not leave floating.

Unused Inputs

- Connect all unused $V_{SENSEP}n$, $V_{SENSEM}n$ and DACM*n* pins to GND. Do not float unused inputs. Refer to Unused ADC Sense Inputs in the Applications Information section of the LTC2977 data sheet.

DAC Outputs

- Select appropriate resistor for desired margin range. Refer to the resistor selection tool in LTpowerPlay for assistance.

Power Supplies

- If powered from VPWR, do not connect the $V_{DD33(A)}$ and $V_{DD33(B)}$ pins together. Each V_{DD33} pin has an independent, internal regulator.

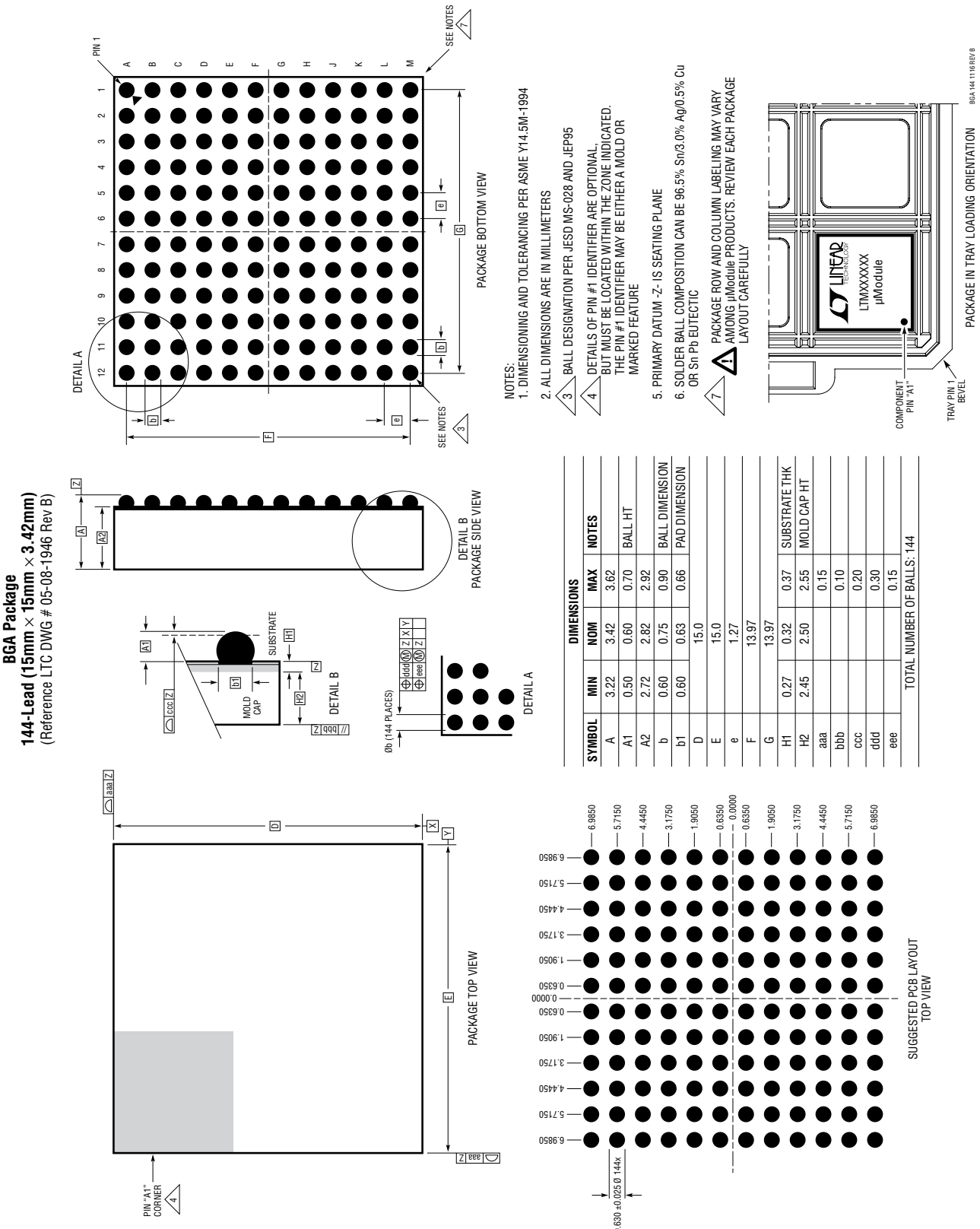
For a more complete list of design considerations and a schematic checklist, see the Design Checklist on the LTM2987 product page.

PACKAGE DESCRIPTION

LTM2987 Component BGA Pinout (Top View)

		1	2	3	4	5	6	7	8	9	10	11	12
Device A	A	WP	V_{DD25}	V_{DD33}	V_{DD33}	V_{IN_SNS}	$V_{SENSEM7}$	$V_{SENSEP7}$	V_{OUT_EN6}	V_{DACM6}	V_{DACP6}	$V_{SENSEM6}$	$V_{SENSEP6}$
	B	PWRGD	SHARE_CLK	V_{PU}	WDI	V_{PWR}	V_{DACM7}	V_{DACP7}	V_{OUT_EN5}	V_{DACM5}	V_{DACP5}	$V_{SENSEM5}$	$V_{SENSEP5}$
	C	SDA	R_{PU3}	FAULTB00	FAULTB10	DNC	GND	V_{OUT_EN7}	V_{OUT_EN4}	V_{DACM4}	V_{DACP4}	$V_{SENSEM4}$	$V_{SENSEP4}$
	D	SCL	R_{PU2}	FAULTB01	FAULTB11	GND	GND	V_{OUT_EN0}	V_{OUT_EN3}	V_{DACM3}	V_{DACP3}	$V_{SENSEM3}$	$V_{SENSEP3}$
	E	CONTROL0	ALERTB	R_{PU1}	R_{PU4}	V_{IN_EN}	V_{DACM0}	V_{DACP0}	V_{OUT_EN2}	V_{DACM2}	V_{DACP2}	$V_{SENSEM2}$	$V_{SENSEP2}$
	F	CONTROL1	ASEL1	ASEL0	REFM	REFP	$V_{SENSEM0}$	$V_{SENSEP0}$	V_{OUT_EN1}	V_{DACM1}	V_{DACP1}	$V_{SENSEM1}$	$V_{SENSEP1}$
Device B	G	WP	V_{DD25}	V_{DD33}	V_{DD33}	V_{IN_SNS}	$V_{SENSEM7}$	$V_{SENSEP7}$	V_{OUT_EN6}	V_{DACM6}	V_{DACP6}	$V_{SENSEM6}$	$V_{SENSEP6}$
	H	PWRGD	SHARE_CLK	V_{PU}	WDI	V_{PWR}	V_{DACM7}	V_{DACP7}	V_{OUT_EN5}	V_{DACM5}	V_{DACP5}	$V_{SENSEM5}$	$V_{SENSEP5}$
	J	SDA	R_{PU3}	FAULTB00	FAULTB10	DNC	GND	V_{OUT_EN7}	V_{OUT_EN4}	V_{DACM4}	V_{DACP4}	$V_{SENSEM4}$	$V_{SENSEP4}$
	K	SCL	R_{PU2}	FAULTB01	FAULTB11	GND	GND	V_{OUT_EN0}	V_{OUT_EN3}	V_{DACM3}	V_{DACP3}	$V_{SENSEM3}$	$V_{SENSEP3}$
	L	CONTROL0	ALERTB	R_{PU1}	R_{PU4}	V_{IN_EN}	V_{DACM0}	V_{DACP0}	V_{OUT_EN2}	V_{DACM2}	V_{DACP2}	$V_{SENSEM2}$	$V_{SENSEP2}$
	M	CONTROL1	ASEL1	ASEL0	REFM	REFP	$V_{SENSEM0}$	$V_{SENSEP0}$	V_{OUT_EN1}	V_{DACM1}	V_{DACP1}	$V_{SENSEM1}$	$V_{SENSEP1}$

PACKAGE DESCRIPTION



DIMENSIONS				
SYMBOL	MIN	NOM	MAX	NOTES
A	3.22	3.42	3.62	
A1	0.50	0.60	0.70	BALL HT
A2	2.72	2.82	2.92	
b	0.60	0.75	0.90	BALL DIMENSION
b1	0.60	0.63	0.66	PAD DIMENSION
D		15.0		
E		15.0		
e		1.27		
F		13.97		
G		13.97		
H1	0.27	0.32	0.37	SUBSTRATE THK
H2	2.45	2.50	2.55	MOLD CAP HT
aaa			0.15	
bbb			0.10	
ccc			0.20	
ddd			0.30	
eee			0.15	
TOTAL NUMBER OF BALLS: 144				

REVISION HISTORY

REV	DATE	DESCRIPTION	PAGE NUMBER
A	08/16	Added EEPROM ECC information and updated Typical Application.	1
		Increased Maximum Solder Temperature from 245°C to 250°C.	2
		Updated DAC Output Update Rate (t_{S_VDACP}) to 500µs from 250µs.	4
		Added Note 4.	7
		Added graph: $V_{OUT\_EN[7:0]}$ Output Voltage vs V_{DD33}.	10
		Updated V_{DD33} and SHARE_CLK pin functions.	11
		Changed MFR_SPECIAL_ID in Table 1.	14
B	07/22	Update V_{OS_ADC} MAX.	3
		Update VDAC Full-Scale MIN Specification.	4
		Remove Temp Dot for DAC INL Specification.	4
		I_{VOUT_ENn} Output Sinking Current at condition Weak Pull-Down Enabled: minimum spec changed from 33µA to 28µA and typical spec changed from 50µA to 43µA.	5
		I_{VOUT_ENn} Output Sinking Current at condition Strong Pulldown Enabled, V_{OUT_ENn} = 0.1V: spec updated to typical value only at room temp.	